

## 12" Oxide wafer

| Description            | Specification               |
|------------------------|-----------------------------|
| Oxide layer THICKNESS  | 1K, 2K,3K,5KA +/-10%A       |
| Oxide layer uniformity | 5%                          |
| Resistivity            | 0.5~100 ohm/cm              |
| Thickness              | 700um+/-25um.               |
| Type                   | P/N type.                   |
| TTV                    | <25um                       |
| BOW/Warp               | <50um                       |
| Diameter               | 300 +/- 0.2 mm              |
| Surface                | Polished/Polished           |
| Particle               | >0.3um, <30ea.              |
| package                | AL-package                  |
| Laser mark             | Front side(4 digits or 12M) |
| Asking price           | USD64 per each.             |